Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Diameter:

1.227 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-94

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.063 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1000.0 repetitive peak reverse voltage, peak total value and 1100.0 nonrepetitive peak reverse voltage

Current Rating Per Characteristic:

125.00 amperes forward current, total rms horsepower metric

Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnpn

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0